

Fully operational write-read-write and random-access

Journal of Applied Physics

47, 3697-3701

DOI: 10.1063/1.323134

Citation Report

#	ARTICLE	IF	CITATIONS
1	Thermomagnetic switching of ferrimagnetic garnet films at their compensation temperature. Journal of Applied Physics, 1976, 47, 3681-3689.	2.5	17
2	MOPS, a magneto-optic photoconductor sandwich for optical information storage. Journal of Applied Physics, 1977, 48, 366-368.	2.5	23
3	Pinning of 180° Bloch walls at etched nuclear tracks in LPE-grown iron garnet films. Journal of Applied Physics, 1977, 48, 5191-5196.	2.5	28
4	Magneto-optic Memories. Optica Acta, 1977, 24, 495-504.	0.7	5
5	Influence of irradiation with high energetic ions on storage properties of magneto-optic (Gd, Bi) <sub>3</sub> (Fe, Tl) <sub>5</sub> O <sub>12</sub> garnet films. Journal of Applied Physics, 1978, 49, 4811-4814.	2.3	29
6	Influence of nuclear tracks on the coercivity of single crystalline (Gd, Bi) <sub>3</sub> (Fe, Ga) <sub>5</sub> O <sub>12</sub> LPE garnet films. Journal of Magnetism and Magnetic Materials, 1979, 10, 97-99.	2.3	14
7	Stress induced magnetocrystalline anisotropy an application to magnetic film devices. Physics Letters, Section A: General, Atomic and Solid State Physics, 1980, 76, 417-418.	2.1	0
8	Interface devices and memory materials. Topics in Applied Physics, 1981, , 111-179.	0.8	15
9	On the feasibility of a scalable opto-electronic CRCW shared memory. , 0, , .		0
10	Optical Memory Systems. , 1978, , 273-289.		1